



Article

A Reinvestigation of a Superhard Tetragonal sp^3 Carbon Allotrope

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Abstract: $I\bar{4}$ –carbon was first proposed by Zhang *et al.*, this paper will report regarding this phase of carbon. The present paper reports the structural and elastic properties of the three-dimensional carbon allotrope $I\bar{4}$ –carbon using first-principles density functional theory. The related enthalpy, elastic constants, and phonon spectra confirm that the newly-predicted $I\bar{4}$ –carbon is thermodynamically, mechanically, and dynamically stable. The calculated mechanical properties indicate that $I\bar{4}$ –carbon has a larger bulk modulus (393 GPa), shear modulus (421 GPa), Young's modulus (931 GPa), and hardness (55.5 GPa), all of which are all slightly larger than those of c-BN. The present results indicate that $I\bar{4}$ –carbon is a superhard material and an indirect-band-gap semiconductor. Moreover, $I\bar{4}$ –carbon shows a smaller elastic anisotropy in its linear bulk modulus, shear anisotropic factors, universal anisotropic index, and Young's modulus.

Keywords: elastic properties; anisotropic properties; electronic structure; carbon allotrope

PACS: 61.50.-f; 62.20.-x; 63.20.dk; 71.20.-b

1. Introduction

The group 14 elements, such as carbon, silicon, and germanium, have attracted much interest and have been extensively studied [1–20]. Carbon is found on the Earth mainly in the form of graphite and diamond. The quest for carbon materials with desired properties is of great interest in both fundamental science and advanced technology. One of the most famous carbon materials is graphene. Recently, some scholars of great research found several carbon allotropes with low-energy metastable structures, such as monoclinic M-carbon [1,2], F-carbon [3], orthorhombic W-carbon [4], Z-carbon [5], H-carbon and S-carbon [6], C-carbon [7], Imma-carbon [8,9], M585-carbon [10], T12-carbon [11], C2/m-16 carbon [12], P222₁-carbon [13], and Cco-carbon [14]. We easily found that these carbon allotropes, with low-energy metastable structures with sp^3 hybridization, could possibly explain the superhard property of materials. Hardness is an important property that determines many of the technological applications of materials. The mechanical properties of some carbon allotropes (such as T-carbon [21] and Y-carbon [22]) are not excellent, as discussed above, but can be improved through modulation [23,24]. At the moment, there are a multitude of metastable carbon allotropes that have been predicted using the quantum-chemical methods of calculation, e.g., evolutionary metadynamics technique [25–28], and Universal Structure Prediction: Evolutionary Xtallography (USPEX) [29–32], or post-graphite superhard phase synthesized by cold-compressing graphite [33–39]. Compressed graphite appears as an initial material for transition to different superhard phases. An ocean of possible carbon modifications can be obtained by combining four-, five-, six-, seven-, even eight-membered carbon rings. The discussion above of carbon allotropes basically adopts this structure. Wang et al. [40] found a dynamically stable and energetically favourable carbon allotrope, i.e., J-carbon. It has a wider

Materials 2016, 9, 484 2 of 15

band gap (5.89 eV within LDA-HSE06) than that of diamond and a larger bulk modulus (395 GPa). Currently, Z-carbon [33,34] is the most stable and hardest material predicted by the theoretical methods compared with other theoretical structures, but it has not exceeded diamond's bulk modulus and hardness. The inclusion in the Z-carbon of additional diamond blocks generates another superhard carbon allotrope family, investigated in [41]. Li *et al.* [42] predicted a new cubic carbon allotrope, namely, C_{96} carbon. Unfortunately, its mechanical properties are not excellent and it cannot be used as a potential superhard material. Recently, another sp^3 carbon allotrope, *i.e.*, diamond nanothread, was synthesized experimentally; Fitzgibbons *et al.* [43] and Zhan *et al.* [44] then reported regarding its mechanical properties. These nanothreads show extraordinary properties, such as strength and stiffness, higher than those of sp^2 carbon nanotubes.

Moreover, $\overline{14}$ –carbon was first predicted in [45]. However, the physical properties, *i.e.*, the structural, mechanical, and electronic properties, of $\overline{14}$ –carbon were not studied in [45], nor in other studies. The physical properties of a novel superhard carbon allotrope with tetragonal $\overline{14}$ symmetry (16 atoms/cell) will be detailed in this paper using first-principles calculations.

2. Materials and Methods

The calculations were performed using the density functional theory (DFT) [46,47] by using the Cambridge Serial Total Energy Package (CASTEP) code [48]. The electron–ionic core interaction was represented using the ultrasoft pseudopotentials [49]. The structural optimizations were conducted using the Broyden–Fletcher–Goldfarb–Shanno (BFGS) minimization [50]. The calculations were performed using the local density approximation (LDA) [51,52] and generalized gradient approximation (GGA) in the form of the Perdew–Burke–Ernzerhof (PBE) [53] exchange correlation potential. The total energy convergence tests showed that convergence to within 1 m·eV/atom was achieved using the above calculation parameters. The electron and core interactions were included by using the ultrasoft pseudopotentials method, with a plane-wave energy cutoff energy of 400 eV, where $2s^22p^2$ are treated as valence electrons for C. Highly dense k-point [54] sampling with a grid spacing of less than $2\pi \times 0.025$ Å⁻¹ (7 × 7 × 7 for I $\overline{4}$ –carbon) in the Brillouin zone was used. The self-consistent convergence of the total energy was 5 × 10⁻⁶ eV/atom; the maximum force on the atom was 0.01 eV/Å; the maximum ionic displacement was within 5 × 10⁻⁴ Å; the maximum stress was within 0.02 GPa.

3. Results and Discussion

3.1. Structural Properties

There is a new tetragonal carbon phase, namely, I4–carbon, which belongs to the I4 space group. The crystal structure of I4-carbon is shown in Figure 1. Different atomic positions are denoted by different colours of spheres. There are five inequivalent carbon atoms in its conventional cell, located at C1: 8g (-0.1219, -0.2709, -0.6225), C2: 8g (0.4044, -0.1809, 0.0492), C3: 8g (0.4812, 0.2514, -0.3772), C4: 2a (0.5000, 0.5000, 0.50000) and C5: 2d (0.0000, 0.5000, 0.7500). The optimized lattice parameters within the GGA and LDA level of I4-carbon at ambient pressure are listed in Table 1. As listed, a = 5.5628 (5.5017) Å and c = 5.5082 (5.4471) Å are within the GGA (LDA) level and c is slightly smaller than a. These lattice parameters are in excellent agreement with the theoretical values predicted by Zhang et al. [45]. The results within GGA are closer to the theoretical values predicted by Zhang et al. [45]; thus, the following discussions use the results of the GGA level. I4–carbon has seven bond lengths, which are also listed in Table 1. Between C1 and C2, C1 and C3, there are two different bond lengths, i.e., 1.5586 and 1.5224 Å, 1.5555 and 1.5207 Å, respectively, within the GGA level. The average bond length of I4–carbon is 1.5510 Å, while it is 1.567 Å and 1.551 Å for C2/m-16 carbon and M carbon, respectively. They are all slightly greater than that of diamond (1.535 Å). The hardness of I4–carbon, C2/m–16 carbon, M carbon, c-BN and diamond is calculated by using Lyakhov and Oganov's model [55]. The hardness of I4-carbon is 55.5 GPa, which is slightly smaller

Materials 2016, 9, 484 3 of 15

than that of C2/m–16 carbon (59.5 GPa) [12] and M carbon (66.6 GPa), approximately half of that of diamond (89.7 GPa), and slightly larger than that of c-BN (49.9 GPa); the hardness of diamond is very close to the result of Ref [55] (91.0 GPa) using the Lyakhov and Oganov's model. The hardness of $I\bar{4}$ –carbon is 83.0 GPa in Ref [45], the main reason for this situation is that the empirical formula may over or underestimate the value of the material's hardness. Most researchers agree that "superhard" materials are those with Hv exceeding 40 GPa. Although there are slight differences between the results of the empirical models above, all of them greatly exceed 40 GPa, indicating that $I\bar{4}$ –carbon is a superhard material.

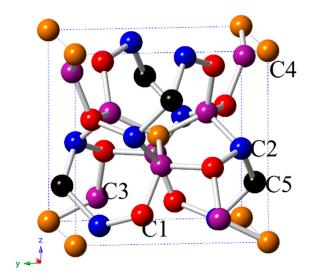


Figure 1. The crystal structure of $I\overline{4}$ –carbon.

Table 1. The calculated lattice parameters (in Å) and bond lengths (in Å) for $I\overline{4}$ –carbon.

Methods	а	с	d _{C1-C2}	d _{C1-C3}	d _{C2-C3}	d _{C2-C5}	d _{C3-C4}
GGA	5.5628	5.5082	1.5586 1.5224	1.5555 1.5207	1.5694	1.5871	1.5430
LDA	5.5017	5.4471	1.5435 1.5036	1.5408 1.5039	1.5531	1.5683	1.5253

3.2. Mechanical Properties

For the tetragonal I $\overline{4}$ -carbon, seven independent elastic constants C_{ij} were determined within the GGA level from the stress of the strained structure with a finite strain. The elastic constants of I4–carbon under different pressures are listed in Table 2. From Table 2, one can find that the mechanical stability of I $\overline{4}$ –carbon satisfies Born's criterion for a tetragonal crystal [56]: $C_{ii} > 0$, i = 1, 3, 4, 6; C_{11} – $C_{12} > 0$; $C_{11} + C_{33} - 2C_{13} > 0$ and $2(C_{11} + C_{12}) + C_{33} + 4C_{13} > 0$, indicating that $I\bar{4}$ -carbon is mechanically stable at 0–100 GPa. Moreover, almost all elastic constants increase with increasing pressure. C_{11} increases the fastest ($dC_{11}/dP = 4.57$), followed by C_{33} ($dC_{33}/dP = 4.24$); C_{44} is the slowest (dC44/dP = 0.63). C_{16} decreases with increasing pressure ($dC_{16}/dP = -0.35$). Furthermore, it is important to explore the dynamic stability and thermodynamic stability for further experimental synthesis. The phonon spectra and the enthalpies as a function of pressure are shown in Figure 2a-d. Clearly, no imaginary mode is shown in the phonon spectra. This strongly confirms that the I4-carbon with the I4 structure is dynamically stable; thus, it is a new metastable phase in the carbon family. The enthalpy of different carbon allotropes is quantified in terms of the following formation enthalpies formula: ΔH = Hcarbon allotropes/ n_1 – Hdiamond/ n_2 , where n denotes the number of atoms in a conventional cell for carbon allotropes or graphite. As shown in Figure 2c,d, the calculated formation enthalpies of I4–carbon are slightly smaller than those of M-carbon below 32.25 GPa. Bulk modulus B and shear

Materials 2016, 9, 484 4 of 15

modulus G are calculated by using the Voigt–Reuss–Hill approximation. It is known that the Voigt bound is obtained by using the average polycrystalline modulus, based on an assumption of uniform strain throughout a polycrystalline, and is the upper limit of the actual effective modulus, while the Reuss bound is obtained by assuming a uniform stress and is the lower limit of the actual effective modulus. The arithmetic average of Voigt and Reuss bounds is referred to as the Voigt-Reuss-Hill approximations. Young's modulus E and Poisson's ratio v are obtained using the following equations: E = 9BG/(3B + G), v = (3B - 2G)/(6B + 2G), respectively. The calculated results of elastic modulus for I4-carbon are also shown in Table 2. The bulk modulus, shear modulus, Poisson's ratio, and Young's modulus all increase with increasing pressure. The bulk modulus increases the fastest, while shear modulus increases the slowest, i.e., dB/dP = 3.30 and dG/dP = 0.86, respectively. Pugh [57] proposed the ratio of bulk to shear modulus (B/G) and Lewandowski [58] proposed Poisson's ratio as indications of a ductile *versus* brittle characteristic. B/G > 1.75 and v > 0.26 for a solid material represents ductility, while B/G < 1.75 and v < 0.26 usually indicate brittleness. From 0 to 100 GPa, $\overline{14}$ –carbon is brittle; namely, the brittleness of I4-carbon decreases with increasing pressure. Compared with other carbon allotropes (P222₁-carbon: 0.872 [13]; C2/m-16 carbon: 0.867 [12]; Imma-carbon: 0.858 [12]; diamond: 0.831 [12]), I4–carbon (0.933) has the least brittleness at ambient pressure.

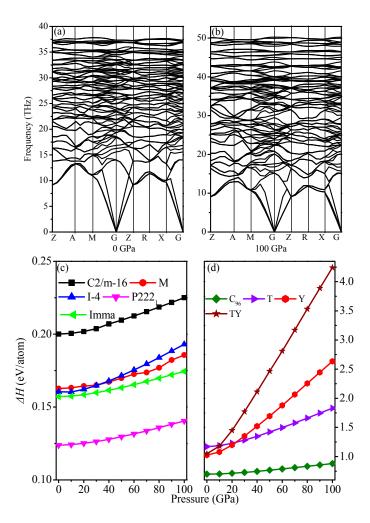


Figure 2. Phonon spectra for $\overline{I4}$ –carbon at 0 GPa (**a**) and 100 GPa (**b**); enthalpies of $\overline{I4}$ –carbon and other carbon allotropes relative to graphite as a function of pressure (**c**,**d**).

Materials 2016, 9, 484 5 of 15

Table 2.	The calculated	elastic constant	ts (in GPa) and elasti	c modulus	(in GPa) of	I4 –carbon at
different	pressures.						

P	C ₁₁	C ₁₂	C ₁₃	C ₁₆	C ₃₃	C ₄₄	C ₆₆	В	G
0	926	133	101	-28	1017	398	472	393	421
10	1015	175	142	-35	1028	408	493	441	434
20	1034	189	153	-40	1081	422	511	460	446
30	1079	220	182	-43	1132	428	528	495	455
40	1128	248	208	-46	1181	436	544	529	466
50	1174	274	235	-49	1229	442	559	563	475
60	1220	304	261	-53	1275	449	573	596	484
70	1263	332	287	-56	1320	454	586	629	491
80	1306	360	303	-59	1364	458	598	661	499
90	1347	387	340	-62	1403	462	608	692	504
100	1383	419	366	-63	1441	461	614	723	507

Incompressibility can reflect the size of the bulk modulus from the other side. The V/V_0 of $I\bar{4}$ –carbon, C2/m–16 carbon, M–carbon, P222₁–carbon, c–BN, and diamond as a function of pressure are shown in Figure 3a. From Figure 3a, it is clear that c–BN shows a weaker incompressibility than that of the other carbon allotropes, while $I\bar{4}$ –carbon exhibits the weakest incompressibility among the carbon allotropes. The order of incompressibility for carbon allotropes and c-BN is diamond > P222₁–carbon > M–carbon > C2/m–16 carbon > $I\bar{4}$ –carbon > c–BN. The bulk moduli of carbon allotropes and c-BN are also in this order: diamond (439 GPa) > P222₁–carbon (409 GPa) > M–carbon (399 GPa) > C2/m–16 carbon (398 GPa) > $I\bar{4}$ –carbon (393 GPa) > c–BN (370 GPa). Regarding the incompressibility of $I\bar{4}$ –carbon in detailed investigations, the lattice parameters a/a_0 and c/c_0 as functions of pressure are illustrated in Figure 3b. Regarding the incompressibility of lattice parameters a/a_0 and c/c_0 , they are very close. The incompressibility of lattice parameter c is slightly larger than that of a. By fitting the calculated data using the polynomial fitting methods, the following relationships at 0 GPa and 0 K are obtained:

$$a/a_0 = 1.96545 \times 10^{-6} P^2 - 7.85386 \times 10^{-4} P + 0.99970 \tag{1}$$

$$c/c_0 = 1.93918 \times 10^{-6} P^2 - 7.79164 \times 10^{-4} P + 0.99965$$
 (2)

where the unit of pressure is GPa. By fitting using the polynomial, it is clear that the incompressibility of lattice parameter c is slightly better than that of a.

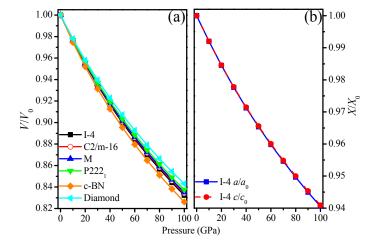


Figure 3. The primitive cell volume V/V_0 as a function of pressure for $I\bar{4}$ –carbon, P222₁-carbon, C2/m-16 carbon, M-carbon, c-BN and diamond (a); lattice constants a/a_0 , c/c_0 compression of $I\bar{4}$ –carbon as a function of pressure (b).

Materials 2016, 9, 484 6 of 15

The defined Debye temperature parameter, which can be interpreted as the temperature at which the highest-frequency mode (and hence every mode) is excited, is of great importance, allowing us to predict the heat capacity at any temperature in an atomic solid. The formula for evaluating the Debye temperature is given by [59]:

$$\Theta_D = \frac{h}{k_B} \left[\frac{3n}{4\pi} \left(\frac{N_A \rho}{M} \right) \right]^{\frac{1}{3}} v_m \tag{3}$$

where h denotes Planck's constant, k_B denotes Boltzmann's constant, n denotes the number of atoms per formula unit, N_A denotes Avogadro's number, M denotes molar mass, and ρ denotes density. The average sound velocity v_m is described by the following formula:

$$v_m = \left[\frac{1}{3} \left(\frac{2}{v_t^3} + \frac{1}{v_l^3} \right) \right]^{-\frac{1}{3}} \tag{4}$$

The transverse and longitudinal elastic wave velocity, v_t and v_l , can be obtained using Navier's equation, as follows [60]:

$$v_t = \sqrt{\frac{G}{\rho}} \text{ and } v_l = \sqrt{\frac{3B + 4G}{3\rho}}$$
 (5)

where B and G are the bulk modulus and shear modulus, respectively. Based on Equation (3), the Debye temperature of $\overline{14}$ –carbon Θ_D = 2024 K. The Debye temperature of $\overline{14}$ –carbon as a function of pressure is plotted in Figure 4a. It is found that the Debye temperature increases with increasing pressure. Furthermore, the greater the pressure, the more slowly the Debye temperature increases. The calculated results of the density, Debye temperature, transverse and longitudinal elastic wave velocity v_t and v_t , and the mean sound velocity v_t at different pressures are listed in Table 3. The density and v_t increase with increasing pressure. With the increase of pressure, the transverse longitudinal elastic wave velocity v_t shows no monotonic increase or decrease. However, the mean sound velocity v_t increases with increasing pressure from 80 to 100 GPa. The main reason is that sometimes v_t increases with increasing pressure and sometimes decreases, *i.e.*, there is no law.

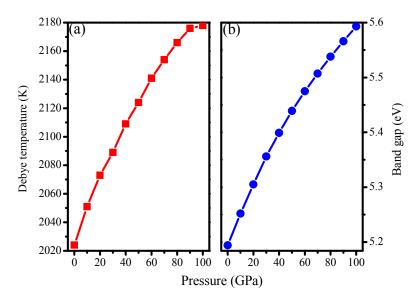


Figure 4. Debye temperature (a) and band gap (b) of $\overline{14}$ –carbon as a function of pressure.

Materials 2016, 9, 484 7 of 15

Table 3. The calculated density (ρ , in g/cm ³), the longitudinal, transverse, and mean elastic wave
velocity $(v_s, v_p, v_m, \text{ in m/s})$, and the Debye temperature $(\Theta_D, \text{ in K})$ for $\overline{I4}$ –carbon.

P	ρ	v_l	v_t	v_m	Θ_{D}
0	3.2764	17,069	11,336	12,398	2024
10	3.3564	17,434	11,373	12,467	2051
20	3.4332	17,529	11,402	12,503	2073
30	3.5059	17,730	11,395	12,513	2089
40	3.5750	17,939	11,415	12,549	2109
50	3.6412	18124	11417	12566	2124
60	3.7045	18303	11427	12589	2141
70	3.7654	18465	11424	12598	2154
80	3.8243	18617	11417	12602	2166
90	3.8814	18751	11400	12594	2176
100	3.9365	18852	11345	12547	2178

3.3. Anisotropic Properties

It is well known that the anisotropy of elasticity is an important implication in engineering science and crystal physics [61], hence, it is worthwhile to investigate the elastic anisotropy of materials. The shear anisotropic factors provide a measure of B_a , B_b , and B_c , i.e., the bulk modulus along the a, b and c axes, respectively, which can be calculated by using the following equations:

$$B_a = a \frac{dP}{da} = \frac{\Lambda}{1 + \alpha + \beta'} \tag{6}$$

$$B_b = b \frac{dP}{dh} = \frac{B_a}{\alpha},\tag{7}$$

$$B_c = c \frac{dP}{dc} = \frac{B_a}{\beta},\tag{8}$$

$$\Lambda = C_{11} + 2C_{12}\alpha + C_{22}\alpha^2 + C_{33}\beta^2 + 2C_{13}\beta(1+\alpha), \tag{9}$$

$$\alpha = \frac{(C_{11} - C_{12})}{(C_{22} - C_{12})},\tag{10}$$

$$\beta = \frac{(C_{22} - C_{12})(C_{11} - C_{13}) - (C_{11} - C_{12})(C_{13} - C_{12})}{(C_{22} - C_{12})(C_{33} - C_{13})}$$
(11)

The calculated B_a , B_b , and B_c at different pressures are shown in Figure 5a. Due to the lattice constant a being equal to b, the bulk modulus along the a-axis is equal to that along the b axis, in other words, $B_a = B_b$. It is clear that B_a , B_b , and B_c increase with increasing pressure and that B_a , B_b (87.69%) increase more than B_c (76.50%). The calculated directional bulk modulus suggests that it is the largest along the a-axis and the smallest along the c-axis, indicating that the compressibility along the c-axis is the smallest, while along the a-axis, is the largest. This is in accordance with the relationships between the ratios a/a_0 , c/c_0 and pressure, as shown in Figure 3b. Therefore, the anisotropy of the linear bulk modulus should also be considered. The anisotropy of the bulk modulus along the a-axis and c-axis with respect to the b-axis can be estimated by:

$$A_{B_a} = \frac{B_a}{B_b}$$
, and $A_{B_c} = \frac{B_c}{B_b}$ (12)

The anisotropy factors of the bulk modulus along the a-axis and c-axis for $\overline{14}$ -carbon at T=0 K as a function of pressure are shown in Figure 5b. Note that a value of 1.0 indicates elastic isotropy and any departure from 1.0 represents elastic anisotropy. The anisotropy of the bulk modulus along the a-axis and c-axis with respect to the b-axis shows that A_{Ba} is elastic isotropy and A_{Bc} is elastic anisotropy.

Materials 2016, 9, 484 8 of 15

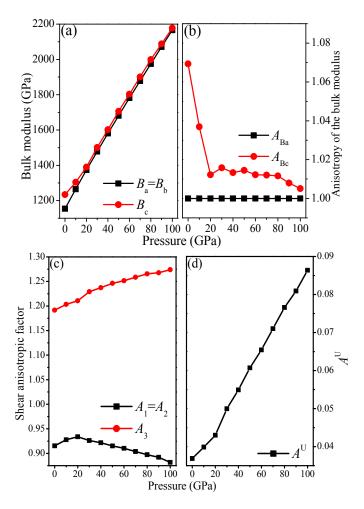


Figure 5. Linear bulk modulus B_a , B_b , and B_c of $I\bar{4}$ –carbon at 0 K as a function of pressure (**a**); anisotropy factors of $I\bar{4}$ –carbon at 0 K as a function of pressure, (**b**) A_{Bb} and A_{Bc} ; (**c**) A_1 , A_2 and A_3 ; (**d**) A^U .

After discussing the anisotropy of the bulk modulus, we now discuss the anisotropy of the shear modulus. The shear anisotropic factors provide a measure of the degree of anisotropy in the bonding between atoms in different planes. The shear anisotropic factor for the $(1\ 0\ 0)$ shear planes between $[0\ 1\ 1]$ and $[0\ 1\ 0]$ directions and the $(0\ 1\ 0)$ shear planes between $[1\ 0\ 1]$ and $[0\ 0\ 1]$ directions is [62]:

$$A_1 = \frac{4C_{44}}{C_{11} + C_{33} - 2C_{13}},\tag{13}$$

For the (0 1 0) shear planes between [1 0 1] and [0 0 1] directions, it is [60]:

$$A_2 = \frac{4C_{55}}{C_{22} + C_{33} - 2C_{23}},\tag{14}$$

For the (0 0 1) shear planes between [1 1 0] and [0 1 0] directions, it is [60]:

$$A_3 = \frac{4C_{66}}{C_{11} + C_{22} - 2C_{12}} \tag{15}$$

For an isotropic crystal, the factors A_1 , A_2 , and A_3 are 1.0, while any value smaller or larger than 1.0 is a measure of the elastic anisotropy possessed by the materials. The anisotropy factors of I $\overline{4}$ –carbon at T=0 K as a function of pressure are shown in Figure 5c. Due to the symmetry of the crystal structure, $C_{11}=C_{22}$, $C_{44}=C_{55}$ and $C_{13}=C_{23}$; thus, $A_1=A_2$. From Figure 5c, A_1 first increases and

Materials 2016, 9, 484 9 of 15

then decreases with increasing pressure, while A_3 increases monotonically with increasing pressure. $I\bar{4}$ –carbon shows elastic anisotropy in the bulk modulus and shear modulus. The universal anisotropic index ($A^U = 5G_V/G_R + B_V/B_R - 6$) combines the shear modulus and bulk modulus to exhibit the anisotropy of the material. The A^U of $I\bar{4}$ –carbon increases with pressure (see Figure 5d), indicating that the anisotropy of $I\bar{4}$ –carbon increases with increasing pressure. The A^U of $I\bar{4}$ –carbon is 0.0369, which is smaller than that of C2/m–carbon (0.0766) and P222₁–carbon (0.0526).

Young's modulus is not always the same in all orientations of a material; it will change depending on the direction of the force vector. Engineers can use this directional phenomenon to their advantage in creating structures. The directional dependence of the anisotropy in Young's modulus is calculated by using the Elastic Anisotropy Measures (ELAM) [63,64] code. The 2D representation of Young's modulus for I4–carbon in the (001), (010), (100), (111), (001), and (101) planes is shown in Figure 6a–f, respectively. The black, red, and blue solid curves represent Young's modulus for I4–carbon in the (001), (010), (100), (111), (001), and (101) planes at 0, 50 and 100 GPa, respectively. It is obvious that the anisotropy of Young's modulus increases with increasing pressure in the (001), (010), (100), (111), (001), and (101) planes. To investigate the anisotropy of Young's modulus in detail, we calculate the maximal and minimal values of Young's modulus for I4–carbon in the (001), (010), (100), (111), (001), and (101) planes and for all possible directions, together with the ratio $E_{\text{max}}/E_{\text{min}}$, which are listed in Table 4. The conclusion from Table 4 is consistent with the conclusion we obtained from Figure 6, i.e., that the anisotropy of Young's modulus increases with increasing pressure in the (001), (010), (100), (111), (001), and (101) planes. Regarding the distribution of Young's modulus in the (001) plane and (001) plane, the maximal and minimal values are the same, while in the (010) plane and (100) plane, they are also the same. The (001) plane and (001) plane exhibit the largest anisotropy of Young's modulus for I4-carbon, while the (101) plane exhibits the smallest anisotropy of Young's modulus. This situation also appears under high pressure. All of the degrees of special plane anisotropy are smaller than the overall performance of the material anisotropy because the minimal value of the entire Young's modulus was not obtained. The anisotropy of Young's modulus of I4–carbon ($E_{\text{max}}/E_{\text{min}} = 1.133$) is slightly smaller than that of C2/m-16 carbon ($E_{\text{max}}/E_{\text{min}} = 1.275$) and P2221-carbon ($E_{\text{max}}/E_{\text{min}} = 1.173$). Thus, I4-carbon shows a smaller elastic anisotropy in its linear bulk modulus, shear anisotropic factors, universal anisotropic index, and Young's modulus.

Table 4. The maximum and minimum values of Young's modulus (in GPa) in different planes and for pressures for $I\bar{4}$ –carbon.

Plane	P	Maximum	Minimum	$E_{\rm max}/E_{\rm min}$
(001)	0	999	887	1.126
	50	1250	1054	1.186
	100	1427	1168	1.222
(010)	0	998	889	1.123
	50	1153	1053	1.095
	100	1292	1150	1.123
(100)	0	998	889	1.123
	50	1153	1053	1.095
	100	1292	1150	1.123
(111)	0	992	888	1.117
	50	1233	1045	1.180
	100	1402	1139	1.231
$(00\overline{1})$	0	999	887	1.126
	50	1250	1054	1.186
	100	1427	1168	1.222
(101)	0	949	885	1.072
	50	1160	1050	1.105
	100	1298	1147	1.132
All	0	999	882	1.133
	50	1250	1042	1.200
	100	1427	1138	1.254

Materials 2016, 9, 484 10 of 15

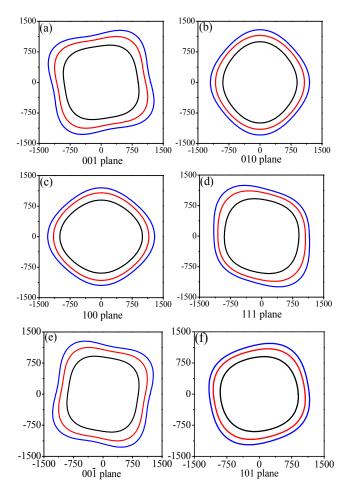


Figure 6. 2D representation of Young's modulus in the (001), (010), (100), (111), (00 $\overline{1}$), and (101) planes for $\overline{14}$ –carbon, shown in (**a**–**f**), respectively.

3.4. Electronic Properties

The band structures of I4-carbon are shown in Figure 7a,b at 0 and 100 GPa, respectively. Semiconductor materials have direct or indirect band gaps. In direct band gap materials, the maximum of the valence band (VBM) and minimum of the conduction band (CBM) occur at the same value of the wave vector, while in indirect band gap materials, they occur for different values of the wave vector. It is obvious that I4-carbon is an indirect-band-gap and wide-band-gap semiconductor material. The VBM of I4–carbon is located at the M point (0.500, 0.500, 0.000), while the CBM is located from point (0.000, 0.000, 0.3667) through G (0.000, 0.000, 0.000) to the Z point (0.000, 0.000, 0.500), whether at ambient pressure or under high pressure. From Figure 7a,b, it is shown that the band gap increases with increasing pressure; more details are shown in Figure 4b; the band gap of I4-carbon increases from 5.19 eV to 5.59 eV. The greater the pressure, the less the band gap increases. To determine the reason why, we calculate the energy values of the CBM and VBM under different pressures. The calculated results are illustrated in Figure 7c. The energy of VBM for I4-carbon is 7.96 eV at 0 GPa and 10.58 eV at 100 GPa; $\Delta E_{VBM} = 2.62$ eV. The energy of CBM for I4–carbon is 13.15 eV at 0 GPa and 16.17 eV at 100 GPa; $\Delta E_{\text{CBM}} = 3.02 \text{ eV}$. $\Delta E_{\text{CBM}} - \Delta E_{\text{VBM}} = 0.40 \text{ eV}$, which is the same as with the band gap increase. In other words, as pressure increases, the conduction band and valence band energy will increase, but the energy of the conduction band will increase more than that of the valence band. The partial density of states (PDOS) of five inequivalent carbon atoms in I4-carbon at 0 and 100 GPa are shown in Figure 8. Figure 8a,c,e,g,i show the partial density of states of five inequivalent carbon atoms at 0 GPa; Figure 8b,d,f,h,j show the partial density of states of five inequivalent carbon atoms at 100 GPa.

Materials **2016**, 9, 484

No matter the position of the carbon atoms, the partial density of states in the conduction band part is, with increasing pressure intensity, near low energy, and the valence band deviates from the Fermi level. The PDOS in the lower energy part is contributed mainly by the C-2s orbitals, while in the other energy part, is contributed mainly by the C-2p orbitals.

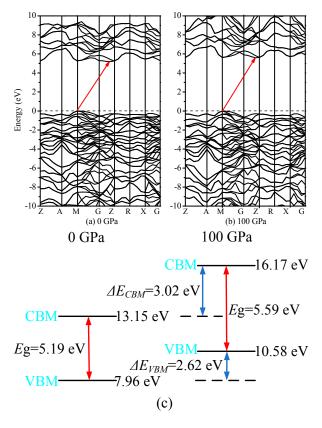


Figure 7. Electronic band structure for the $I\bar{4}$ –carbon at ambient pressure (a) and 100 GPa (b); the calculated energy values of CBM and VBM under different pressures (c).

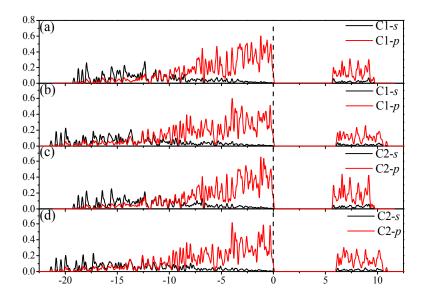


Figure 8. Cont.

Materials 2016, 9, 484

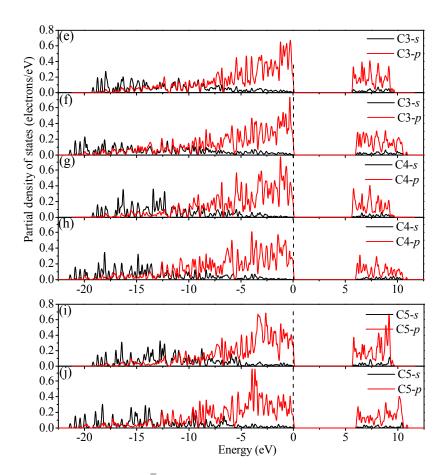


Figure 8. Partial density of state for $\overline{14}$ –carbon; $(\mathbf{a}, \mathbf{c}, \mathbf{e}, \mathbf{g}, \mathbf{i})$ are at ambient pressure, while $(\mathbf{b}, \mathbf{d}, \mathbf{f}, \mathbf{h}, \mathbf{j})$ are at 100 GPa.

4. Conclusions

In conclusion, the low-energy metastable structures of $I\overline{4}$ –carbon have been systematically investigated based on the density functional theory. The related enthalpy, elastic constants and phonon spectra confirm that the newly-predicted $I\overline{4}$ –carbon is thermodynamically, mechanically, and dynamically stable. As a potential superhard material for engineering applications, the mechanical properties of $I\overline{4}$ –carbon indicate that it is a superhard material. $I\overline{4}$ –carbon shows a smaller anisotropy in its linear bulk modulus, shear anisotropic factors, universal anisotropic index, and Young's modulus. The band structure shows that $I\overline{4}$ –carbon is an indirect-band-gap and wide-band-gap semiconductor material. Finally, the calculations of its mechanical properties reveal that $I\overline{4}$ –carbon possesses a high bulk and shear modulus as well as a low Poisson's ratio and B/G ratio (<1.75). Moreover, $I\overline{4}$ –carbon has a larger Debye temperature (Θ_D = 2024 K). Due to their wide-band-gap and higher bulk moduli, hardness, they are attractive for semiconductor device applications and superhard material with potential technological and industrial applications.

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Conflicts of Interest: The authors declare no conflict of interest.

Materials **2016**, 9, 484

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